TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7WH157FU, TC7WH157FK

2-CHANNEL MULTIPLEXER

The TC7WH157 is an advanced high speed CMOS 2-CHANNEL MULTIPLEXER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. It consists of 2-input digital multiplexers with common select and strobe inputs.

When the STROBE input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

- High Speed t_{pd} = 4.1ns (Typ.) at
 - $\dot{V}_{CC} = 5V$
- Low Power Dissipation $\dots I_{CC} = 4\mu A$ (Max.) at Ta = 25°C
- High Noise Immunity $\cdots \cdots \vee V_{NIH} = V_{NIL} = 28\%$ V_{CC} (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays $\cdots t_{pLH} = t_{pHL}$ Wide Operating Voltage Range \cdots V_{CC} (opr) = 2~5.5V
- Low Noise

MARKING



PIN ASSIGNMENT (TOP VIEW)



980508EBA2

- 980508EBA2
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Weight SSOP8-P-0.65 : 0.02g (Typ.) SSOP8-P-0.50A : 0.01g (Typ.)

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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage Range	Vcc	-0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	V	
DC Output Voltage	Vout	-0.5~V _{CC} +0.5	V	
Input Diode Current	Чк	- 20	mA	
Output Diode Current	Іок	± 20	mA	
DC Output Current	Ιουτ	± 25	mA	
DC V _{CC} /Ground Current	lcc	± 50	mA	
Pewer Dissinction	D-	300 (SM8)	mW	
Power Dissipation	PD	200 (US8)		
Storage Temperature	T _{stg}	- 65~150	°C	
Lead Temperature (10 s)	Т	260	°C	

LOGIC DIAGRAM



TRUTH TABLE

	INP	OUTPUTS			
ST	SELECT	А	В	Y	Ϋ́
Н	×	×	×	L	Н
L	L	L	×	L	Н
L	L	Н	×	Н	L
L	Н	×	L	L	Н
L	Н	×	Н	Н	L

x : Don't care

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2.0~5.5	V
Input Voltage	VIN	0~5.5	V
Output Voltage	Vout	0~V _{CC}	V
Operating Temperature T _{opr}		- 40~85	°C
Input Rise and Fall Time	dt/dv	$0 \sim 100 (V_{CC} = 3.3 \pm 0.3 V)$	ns/V
input Rise and Fail fille		$0 \sim 20 (V_{CC} = 5 \pm 0.5V)$	1157 V

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		Vcc	Ta = 25°C			Ta = −40~85°C		UNIT
CHARACTERISTIC STWIBO		TEST CONDITION		(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High Loval				2.0	1.50	—	—	1.50	—	
Input Voltage	High-Level VIH —		_	3.0~ 5.5	V _{CC} ×0.7	_	_	V _{СС} ×0.7		V
Low-Level				2.0		—	0.50	—	0.50	
Input Voltage	VIL		_	3.0~ 5.5		_	V _{CC} ×0.3	_	V _{CC} ×0.3	V
		V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	—	1.9	—	V
High-Level	VOH		l _{OH} = -50μA	3.0	2.9	3.0		2.9	—	
Output Voltage				4.5	4.4	4.5		4.4	_	
			$I_{OH} = -4mA$	3.0	2.58	_	—	2.48		
			$I_{OH} = -8mA$	4.5	3.94	_	_	3.80		
	VOL	V _{IN} = V _{IH}	I _{OL} = 50 µA	2.0		0.0	0.1	_	0.1	v
Low-Level				3.0		0.0	0.1	—	0.1	
Output Voltage				4.5		0.0	0.1	—	0.1	
			I _{OL} = 4mA	3.0		—	0.36	—	0.44	
			I _{OL} = 8mA	4.5			0.36		0.44	
Input Leakage Current	IIN	V _{IN} = 5.5V or GND		0~ 5.5	<u> </u>	_	±0.1		± 1.0	μΑ
Quiescent Supply Current	lcc	V _{IN} =V _{CC} or GND		5.5			2.0		20.0	μΑ

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = −40~85°C		UNIT	
			V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
			3.3 ± 0.3	15	_	6.2	9.7	1.0	11.5	ns
Propagation Delay Time	t _{pLH}		5.5 ± 0.5	50		8.7	13.2	1.0	15.0	
(A, B-Y)	t _{pHL}		5.0 ± 0.5	15		4.1	6.4	1.0	7.5	
(A, B-T)			5.0 ± 0.5	50		5.6	8.4	1.0	9.5	
Propagation Delay Time (SELECT-Y)	t _{pLH} t _{pHL}	3.3±0.3	15		8.4	13.2	1.0	15.5		
			5.5 ± 0.5	50		10.9	16.7	1.0	19.0	ns
			5.0 ± 0.5	15		5.3	8.1	1.0	9.5	
		5.0 -	5.0 ± 0.5	50		6.8	10.1	1.0	11.5	
Propagation Delay Time (ST-Y)	t _{pLH}		3.3±0.3	15		8.7	13.6	1.0	16.0	ns
				50		11.2	17.1	1.0	19.5	
	t _{pHL}		5.0 ± 0.5	15		5.6	8.6	1.0	10.0	
		5.0 ± 0.5	50		7.1	10.6	1.0	12.0		
Input Capacitance	CIN					4	10		10	рF
Power Dissipation Capacitance	C _{PD}	(Note 1)				20	_	_	_	рF

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3ns)

(Note 1) : C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

TYP. IMIT UNIT **SYMBOL TEST CONDITION** CHARACTERISTIC V_{CC} (V) Quiet Output V $C_L = 50 pF$ 5.0 0.3 0.8 VOLP Maximum Dynamic VOL **Quiet Output** 5.0 -0.3 - 0.8 V $C_L = 50 pF$ VOLV Minimum Dynamic VOL Minimum High Level V 5.0 3.5 VIHD $C_L = 50 pF$ ____ **Dynamic Input Voltage** Maximum Low Level $C_L = 50 pF$ 5.0 1.5 ٧ VILD Dynamic Input Voltage

NOISE CHARACTERISTICS (Ta = 25°C, Input $t_r = t_f = 3ns$)

INPUT EQUIVALENT CIRCUIT



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OUTLINE DRAWING SSOP8-P-0.65

Unit : mm





Weight : 0.02g (Typ.)

OUTLINE DRAWING SSOP8-P-0.50A

Unit : mm





Weight : 0.01g (Typ.)